Eigenstate-analysis using Sakurai-Sugiura method with O(N)-DFT code CONQUEST

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2018/8/17 @ ELSI workshop

Today's topics

 Electronic structure analysis of large materials using Sakurai-Sugiura (SS) method and CONQUETS

Introduction of CONQUEST O(N) DFT Multi-site method

O(N)-DFT + SS

Multi-site method + SS

Large-scale DFT calculations



Large-scale model is needed to represent specific atomic and electronic structures



Scales cubically to system size (# of atoms *N*) [**O(N³)**]

Usually ≤ 1,000 atoms

Large-scale DFT with CONQUEST

Concurrent O(N) QUantum Electronic Structure Technique [1]

DFT code for large-scale systems



Large-scale DFT with CONQUEST

Concurrent O(N) QUantum Electronic Structure Technique [1]

DFT code for large-scale systems

- Local orbital functions
- Order-*N* method (Density matrix minimization)
- High parallel efficiency

Local orbital functions



Finite-element (B-spline) basis (akin to plane-wave functions)

Pseudo atomic orbital (PAO) basis

$$\chi_{\mu}(r) = \chi_{i}^{\zeta lm}(r) = R_{i}^{l\zeta}(r) Y_{i}^{lm}(\mathbf{r})$$

 ζ ... Radial functions l ... Angular momentum number m ... Magnetic quantum number

Radial functions Spherical harmonic functions

How to optimize electronic density

O(N³)

Diagonalization

$HC = \varepsilon SC$

H: Electronic Hamiltonian

- **S** : Overlap matrix
- **C** : Eigenvectors (Bands/MOs)
- ε : Eigenvalues (Band/MO energies)

by using Scalapack

• Density matrix minimization $\rightarrow O(N)$

O(N) in CONQUEST

Density matrix minimization (DMM)

$$E_{\text{tot}} = E_{\text{T}} + E_{\text{ps}} + E_{\text{H}} + E_{\text{xc}} + E_{\text{M}}$$

$$E_{\text{T}} = -\frac{\hbar^{2}}{m} \int d\mathbf{r} \left[\nabla^{2} \rho(\mathbf{r}, \mathbf{r}') \right]_{\mathbf{r}=\mathbf{r}'} \qquad \rho(\mathbf{r}, \mathbf{r}') = \sum_{i} f_{i} \psi_{i}(\mathbf{r}) \psi_{i}^{*}(\mathbf{r}')$$

$$E_{\text{ps}} = 2 \int d\mathbf{r} d\mathbf{r}' V_{ps}(\mathbf{r}', \mathbf{r}) \rho(\mathbf{r}, \mathbf{r}') \qquad = \sum_{\alpha\beta} \phi_{\alpha}(\mathbf{r}) K_{\alpha\beta} \phi_{\beta}^{*}(\mathbf{r}')$$

$$E_{\text{H}} = \frac{1}{2} \int d\mathbf{r} d\mathbf{r}' n(\mathbf{r}) n(\mathbf{r}') / |\mathbf{r} - \mathbf{r}'| \qquad n(\mathbf{r}) = 2\rho(\mathbf{r}, \mathbf{r})$$

$$E_{\text{xc}} = \int d\mathbf{r} n(\mathbf{r}) e_{\text{xc}} [n(\mathbf{r})]$$

$$\frac{\partial L}{\partial L} = 6 \left(SLH + HLS \right)_{\alpha\beta} - 4 \left(SLSLH + SLHLS + HLSLS \right)_{\alpha\beta}$$

 $L = Auxiliary density matrix$

[3] E. Hernandez and M. J. Gillan, PRB_51_10157 (1995) [4] E. Hernandez, M. J. Gillan and C. M. Goringe, PRB_53_7147 (1996) 8

O(N) in CONQUEST

Density matrix minimization (DMM)



Spacial cutoff for $L \Rightarrow O(N)$

Capability of CONQUEST

Geometry optimization





STM of Ge hut cluster on Si surface [Y.-W. Mo et al. PRL 65, 1020 (1990).]



About 200,000 atoms

Optimized geometry by CONQUEST [Miyazaki et al., JPSJ, 77, 123706 (2008).]

STM, STS

STM picture of Si (100) surface (-1.5eV)

Exptl

CONQUEST





4.6 nm

Ab initio MD





Hydrated DNA (**3,439 atoms**) PBE/SZP [T. Otsuka et al, in preparation.]

Si (**32,768 atoms**) LDA/DZP Combination with extended Lagrangian method [M. Arita et al, JCTC, 10, 5419 (2014).]

TDDFT, Constraint DFT, EXX, Blue-moon ensemble simulation,

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Eigenstates with O(N) in CONQUEST

O(N) method

- Cow cost: O(N)
- Energies and geometries
- Metals??

8 No 1-e⁻ wave functions (Bands, MOs)

Electronic states:

Orbital pictures Density of states STM images ... (IPs, EAs, excitation energies)

Sakurai-Sugiura method:

Projection method to obtain

eigenstates in a finite range

Sakurai-Sugiura method

Projection method to obtain the eigenstates in a **finite range**



(1) N simultaneous linear equations (number of integration points on the curve)

$$\left(\boldsymbol{\omega}_{j}\mathbf{B}-\mathbf{A}\right)\mathbf{y}_{j}=\mathbf{v}$$
 $\boldsymbol{\omega}_{k}=\boldsymbol{\gamma}+R_{D}\exp\left(\frac{2\pi i}{N}k\right), (k=0,1,\cdots,N-1)$

(2) m×m diagonalization (number of states in the region) $\mathbf{H}_{m}^{<} - \lambda \mathbf{H}_{m}$

$$\mathbf{H}_{m} \coloneqq \begin{pmatrix} \mu_{0} & \mu_{1} & \cdots & \mu_{m-1} \\ \mu_{1} & \mu_{2} & \cdots & \mu_{m} \\ \vdots & \vdots & \ddots & \vdots \\ \mu_{m-1} & \mu_{m} & \cdots & \mu_{2m-2} \end{pmatrix} \mathbf{H}_{m}^{<} \coloneqq \begin{pmatrix} \mu_{1} & \mu_{2} & \cdots & \mu_{m} \\ \mu_{2} & \mu_{3} & \cdots & \mu_{m+1} \\ \vdots & \vdots & \ddots & \vdots \\ \mu_{m} & \mu_{m+1} & \cdots & \mu_{2m-1} \end{pmatrix}$$

 $\mu_{k} = \frac{1}{2\pi i} \int_{\Gamma} \frac{f(z)}{(z-\gamma)^{k+1}} dz \quad \mu_{k} \approx \hat{\mu}_{k} \coloneqq \frac{1}{N} \sum_{j=0}^{N-1} (\omega_{j} - \gamma)^{k+1} f(\omega_{j}), \quad (k = 0, 1, \cdots) f_{j} \leftarrow \mathbf{u}^{\mathrm{H}} y_{j}, \quad (j = 0, \cdots, n-1)$

T. Sakurai, H. Sugiura, J. Comput. Appl. Math. 159, 119 (2003).

Sakurai-Sugiura method



 $N_{\rm SS}$ = number of quadrature points

 $M_{\rm SS}$ = number of complex moments

 L_{SS} = number of columns of the source matrix V ($M_{SS}L_{SS} > m$)

Estimate the number of eigenstates in the region stochastically by using Sylvester' s law of inertia

T. Sakurai et al., Journal of Algorithms & Computational Technology, 7, 249 (2013).

Construct Hamiltonian and overlap matrices with **CONQUEST**

- (sum over k-points)
- (save only lower-triangle elements, larger than threshold)

Eigenstate calculation with Sakurai-Sugiura calculations with **zPares**

Read eigenvectors and eigenvalues with **CONQUEST** MO / Band information \longrightarrow Electronic properties STM pictures

A. Nakata, Y. Futamura, T. Sakurai, D. R. Bowler, T. Miyazaki, J. Chem. Theory. Comput., 13, 4146 (2017) [CQ] http://www.order-n.org [Z-pares] http://zpares.cs.tsukuba.ac.jp/

STM images

P₂ on Si(100)







by PACS-IX (Intel Xeon E5-2670v2) in Univ of Tsukuba

Large systems

Ge hut cluster on Si(001)

Charge distributions



S. Arapan, D. R. Bowler, T. Miyazaki, arXiv:1510.00526.

± 0.01eV around Fermi level 213,633 states 43 states (GGA/SZP)

atoms	node	time
23,737	64	146
194,573	6,400	2,399

 $(N_{\rm SS}=16, M_{\rm SS}=8, L_{\rm SS}=64)$

with K computer

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Large-scale DFT with CONQUEST

Concurrent O(N) QUantum Electronic Structure Technique [1]

DFT program for large scale systems

- High parallel efficiency
- Order-*N* method (Density matrix minimization)
- Local orbital function (support function)

Localized in finite region around each atom \rightarrow sparse

Cost scales cubically to the number of functions

Diagonalization aN^3

Order-N bN

Multi-site functions

No contraction

Primitive functions

Single-site contraction

$$\phi_{i\alpha}(r) = \sum_{\varsigma \in i} c_{i\alpha}^{\varsigma lm} \chi_i^{\varsigma lm}(r)$$

Linear combination of AOs on each atom

Multi-site contraction



$$\phi_{i\alpha}(r) = \sum_{k}^{neighbors} \sum_{\varsigma lm \in k} C_{i\alpha}^{k\varsigma lm} \chi_{k}^{\varsigma lm}(r)$$

Linear combination of AOs in cutoff region

Contract to be **minimal size** keeping primitive AOs' accuracy

Gradient wrt coefficients

$$\frac{\partial E}{\partial C_{i\alpha,k\mu}} = \frac{\partial E}{\partial \phi_{i\alpha}} \frac{\partial \phi_{i\alpha}}{\partial C_{i\alpha,k\mu}} = \frac{\partial E}{\partial \phi_{i\alpha}} \chi_{k\mu}$$

$$\frac{\partial E}{\partial \phi_{i\alpha}(\mathbf{r})} = 4 \sum_{\beta} \left[K_{\alpha\beta} \hat{H} + G_{\alpha\beta} \right] \phi_{j\beta}(\mathbf{r})$$
Diag. $G_{\alpha\beta} = \sum_{n} f_n \varepsilon_n u_{n\alpha} u_{n\beta}^*$
 $K_{\alpha\beta} = \sum_{n} f_n u_{n\alpha} u_{n\beta}^*$
O(N) $G_{\alpha\beta} = 3(LHL)_{\alpha\beta} - 2(LSLHL + LHLSL)_{\alpha\beta}$
 $K_{\alpha\beta} = 3(LSL)_{\alpha\beta} - 2(LSLSL)_{\alpha\beta}$

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Advantages of multi-site method

Applicable to metallic systems

Cutoff is introduced for support functions but not for wave functions

Improve accuracy as much as we want (ex) Si atom

PrimitiveMulti-site support functionsDZP134TZDP224

Always to be minimal size

Computational time

DNA in water



	Primitive AO	Multi-site SFs	
	(DZP)	(8 bohr)	(16 bohr)
# of functions	27883	4744	4744
Time [sec.]			
Matrix construction	28.0	34.5	484.8
Diagonalziation	12317.4	627.7	566.3
Gradient of coefficient	s —	4.3	25.7

PBE / DZP HA8000t (Kyushu Univ) 96 cores parallel

Large reduction! (about 1/12)

DOS of DNA in water (8 bohr)

Cutoff *r*_{MS} = 8.0 bohr

Black: Primitive AO (DZP) Red : Multi-site SFs



DOS of DNA in water (8 bohr)

Cutoff $r_{\rm MS}$ = 8.0 bohr

Black: Primitive AO (DZP)

- Red : Multi-site SFs
- Blue : Primitive AO (DZP) with charge of multi-site SFs



MOs of DNA in water



Investigation of eigenstates (1e- wave functions) becomes available even with O(*N*) method by using Sakurai-Sugiura method

Multi-site method makes available accurate calculation with low computational cost simulation of large metallic systems



Metallic nanoparticles



MO pictures of DNA